

## MBR1635 - MBR1660

### **Features**

- Low power loss, high efficiency.
- High surge capacity.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current capacity, low forward voltage drop.
- Guard ring for over voltage protection.





# **Schottky Rectifiers**

### Absolute Maximum Ratings\*

T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter		Value			
		1635	1645	1650	1660	1
$V_{RRM}$	Maximum Repetitive Reverse Voltage	35	45	50	60	V
I <sub>F(AV)</sub>	Average Rectified Forward Current .375 " lead length @ T <sub>A</sub> = 125°C	16		Α		
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave		150			
T <sub>stg</sub>	Storage Temperature Range		-65 to +175			
TJ	Operating Junction Temperature		-65 to +150			

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
P <sub>D</sub>	Power Dissipation	2.0	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	60	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	1.5	°C/W

### Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Device				Units
		1635	1645	1650	1660	1
V <sub>F</sub>	Forward Voltage $I_{F=}$ 16 A, $T_{C}$ = 25°C $I_{F=}$ 16 A, $T_{C}$ = 125°C	_	63 57	0.0		V
I <sub>R</sub>	Reverse Current @ rated $V_R$ $T_A = 25^{\circ}C$ $T_A = 125^{\circ}C$	0.2 40		1.0 50		mA mA
I <sub>RRM</sub>	Peak Repetitive Reverse Surge Current 2.0 us Pulse Width, f = 1.0 KHz	1.0 0.5		5	Α	

## **Schottky Rectifier**

(continued)

## **Typical Characteristics**

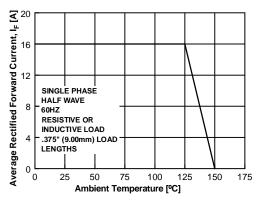


Figure 1. Forward Current Derating Curve

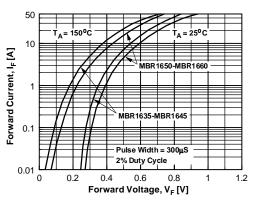


Figure 3. Forward Voltage Characteristics

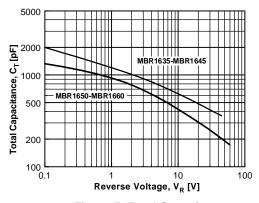


Figure 5. Total Capacitance

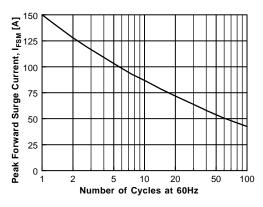


Figure 2. Non-Repetitive Surge Current

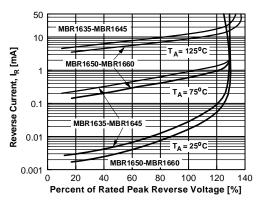


Figure 4. Reverse Current vs Reverse Voltage

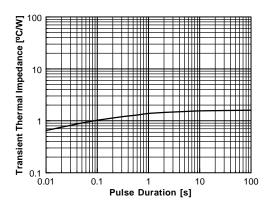


Figure 6. Thermal Impedance Characteristics

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